Photoelectrochemical Operation of a Surface-Bound, Nickel-Phosphine H2 Evolution Catalyst on p-Si(111): A Molecular Semiconductor|Catalyst Construct

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Photoelectrochemical Operation of a Surface-Bound, Nickel-Phosphine H₂ Evolution Catalyst on p-Si(111): A Molecular Semiconductor|Catalyst Construct

Junhyeok Seo, Ryan T. Pekarek and Michael J. Rose*

We demonstrate the covalent attachment and catalytic function of a nickel-phosphine H₂ evolution catalyst to a p-Si(111) photoelectrode. The covalently assembled semiconductor|molecular construct achieves a synergistic improvement (ΔF_{onset} = +200 mV) as compared to a solution of [(PNP)Ni]+ in contact with a p-Si(111)|CH₃ photoelectrode.

The integration of molecular catalysts with light-absorbers (semiconductors) remains at the pinnacle of challenges facing the molecular catalysis branch of solar fuels research. Additionally, retaining the earth abundant nature of each component is essential to promoting the feasibility and widespread application of such a device. Silicon is an excellent candidate as a putative light absorber in a parallel or tandem system, due to its ideal band gap (Eg = 1.12 eV) for the absorption of low energy sunlight to drive the 2H→H₂ conversion. In the arena of molecular catalysts, p-type silicon has been used as a photocathode with free catalysts in solution, and silicon also shows great promise due to developing coupling methods to covalently attach molecular species to fully passivated surfaces. In this regime, the Si(111) surface presents one particular advantage over the Si(100) orientation used in most materials-based approaches: the rigidly perpendicular orientation of Si–X bonds on Si(111) renders it uniquely suited for molecular modification. However, its need for extreme bonding regularity (to prevent surface defect sites) requires molecular passivation – typically by methylation.

In the last decade, the development of molecular catalysts for electrochemical dihydrogen (H₂) generation has blossomed and matured. The families of Co/Fe tetraimines investigated by Artero and Fontecave, Peters, and others as well as the nickel phosphines developed by DuBois and Bullock have achieved remarkable operating parameters (TOF > 100,000 s⁻¹). Ni-phosphines, E_{cat} = −50 to −200 mV vs NHE, Co-N4 complexes. Indeed, a multitude of researchers have grafted derivative of these catalysts onto electrochemically active substrates such as glassy carbon, HOPG, IT0, graphene, and carbon nanotubes. However, the challenge of incorporating such catalysts onto photo-electrochemically active substrates remains open. In this work, we report that covalent attachment of a DuBois-type PNP Ni catalyst (substituted with phenyl units substituent on phosphine and amine) to a p-Si(111) substrate affords H₂ generation from the surface-bound catalyst.

We first devised a surface linker that would be amenable to selective lithiation (for attachment), while retaining a second functional group to participate in Pd-catalyzed coupling reaction. The para bromo- and triflate-functional groups on a phenyl unit were ideal in this regard. A lithiated linker was generated via treatment of para-triflatobromobenzene with 0.9 equiv of n-BuLi in THF at −70 °C for 1 h. The selective Br site lithiation and the persistence of the –OTf group was confirmed by H and F NMR spectroscopy. Indeed, a multitude of researchers have grafted derivative of these catalysts onto electrochemically active substrates such as glassy carbon, HOPG, IT0, graphene, and carbon nanotubes. However, the challenge of incorporating such catalysts onto photo-electrochemically active substrates remains open. In this work, we report that covalent attachment of a DuBois-type PNP Ni catalyst (substituted with phenyl units substituent on phosphine and amine) to a p-Si(111) substrate affords H₂ generation from the surface-bound catalyst.

Scheme 1. Synthetic approach to functionalization of p-Si(111)|Cl substrates with molecular linkers: Negishi coupling of catalyst ligand to surface linker, metatation with nickel(II) source, and capping with an exogenous PNP ligand.

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To promote coupling of the PNP ligand (PNP = \( \text{Ph}_2\text{PCH}_2\text{NCH}_2\text{PPh}_3 \)), the triflate group was activated by treatment of the surface with a dilute solution of [Pd(PPh\(_3\))Cl\(_2\)] in toluene at room temperature, thus generating the surface-bound organometallic Pd\(^{II}\) intermediate. In a separate vessel, Br(C\(_6\)H\(_5\))PdCl\(_2\) was lithiated with n-BuLi at –60 °C in THF, and ZnCl\(_2\) was reacted with the lithiate at room temperature (Scheme 1). The activated Pd\(^{II}\)-bound sample was then immersed in the solution of the ZnCl\(_2\)-adduct, and the reaction heated at 80 °C for 4 h. The resulting surface was rinsed and sonicated thoroughly in THF to remove any adventitious entities (carbon, Mg, Cl\(_2\), etc.). The coupling reaction thus generated the ligand-modified surface as evidenced by the new N 1s XPS signal (\( \theta_{Ni} = 21.2 \pm 6.8\%\), Fig. 1c), the diminished triflato F 1s feature (\( \theta_{OTf} = 5.5 \pm 2.0\%\) at 681.8 eV, Fig. 1b), and subsequent metalation studies (vide infra). Some remaining inorganic F was also detected at 684.5 eV (Fig. 1b).

Interestingly, metalation of the Si(C\(_6\)H\(_5\))PNP interface could be achieved only under specific conditions. For example, treatment of the Si(C\(_6\)H\(_5\))PNP surface with [Ni(H\(_2\)O)\(_2\)]X (X = BF\(_4\), ClO\(_4\)) in MeCN did not lead to any nickel incorporation, as judged by the Ni 2p XPS signal. However, drying the nickel-containing MeCN solution with Na\(_2\)SO\(_4\) for several hours prior to metalation did effect metalation of the Si(C\(_6\)H\(_5\))PNP surface (\( \theta_{Ni} = 24.6 \pm 0.8\%\), \( \theta_{Ni} = 59.3 \pm 13.4\%\), Fig. 1c and 1d). In contrast, treatment of the Si(111)(C\(_6\)H\(_5\))OTf surface with the same nickel(II) solution did not result in any significant incorporation of nickel (\( \theta_{Ni} < 0.5\%\)). Intriguingly, re-treatment of the metalated surface with ‘wet’ MeCN (0.1 % H\(_2\)O for 1 h) did not abstract the surface-bound Ni, indicating the kinetic stability of the surface-bound Si(C\(_6\)H\(_5\))PNP-Ni(MeCN) \((=\text{Si-PNP}^1-\text{Ni})\) moiety. Also, the metallation did not alter the surface recombination velocity (SRV, Table 1), indicating a simple binding event at the surface – i.e. no deposition of Ni\(^0\) (also evidenced by XPS binding energy eV values). Overall, the observed coordination chemistry conditions required for metalation reinforce the notion of the molecular nature of the PNP-Ni\(^0\) interaction.

### Table 1. High resolution XPS quantification (% atop sites) of each element coverage (or functional group, OTf) determined for the indicated Si substrates; (right) surface recombination velocities (S).

<table>
<thead>
<tr>
<th>Substrate</th>
<th>OTF (F) (%)</th>
<th>N (%)</th>
<th>Ni (%)</th>
<th>SRV (S) (cm s(^{-1}))</th>
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<tr>
<td>Si(C(_6)H(_5))OTf</td>
<td>21.8±1.0</td>
<td>&lt; 0.5</td>
<td>&lt; 0.5</td>
<td>1372±29.8</td>
</tr>
<tr>
<td>Si(C(_6)H(_5))PNP</td>
<td>5.5±2.0</td>
<td>21.2±6.8</td>
<td>&lt; 0.5</td>
<td>2415±26.2</td>
</tr>
<tr>
<td>Si-PNP(^{0})-Ni</td>
<td>6.9±2.5</td>
<td>59.3±13.4</td>
<td>24.6±0.8</td>
<td>2395±26.3</td>
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<tr>
<td>Si-PNP(^{0})-Ni</td>
<td>9.7±2.9</td>
<td>41.9±4.9</td>
<td>19.1±5.7</td>
<td>2547±46.3</td>
</tr>
<tr>
<td>Si-PNP(^{0})-Ni</td>
<td>4.98</td>
<td>26.2</td>
<td>15.6</td>
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### Notes

\( ^{20} \)Fig. 1: High resolution XPS spectra of (a) Si 2p, (b) F 1s, (c) N 1s, and (d) Ni 2p for the following surfaces: Si(C\(_6\)H\(_5\))OTf (black), Si(C\(_6\)H\(_5\))PNP (red), Si-PNP\(^{0}\)-Ni (green), and Si-PNP\(^{0}\)-Ni (blue). Data collection: Si 2p, F 1s, N 1s, Ni 2p. \( \lambda_{app} = 1200, 2000, 4800 \) ms (respectively).

To further demonstrate covalent attachment and electronic communication of the PNP-Ni(MeCN)\(_2\) moiety, photoelectrochemical studies were pursued. The cyclic voltammogram (CV, Fig. 2) of the integrated Si-PNP\(^{0}\)-Ni photocathode was obtained in MeCN electrolyte under \( N_2 \) atmosphere (glove box) illuminated conditions (broadband LED 33 mW cm\(^{-2}\); note: the current was not light-limited under any tested condition). The primary cathodic features are observed at \( \sim 0.22 \) V vs NHE (all potentials referenced to \( \text{Fe/Fe}^+ \) as internal standard, then converted to NHE by adding 0.626 V). The increase of current in the cathodic wave at \( \sim 0.22 \) V vs NHE corresponds to the Ni(II/I) conversion (\( F_2 \) for Ni(II/I) = 0.215 V vs NHE), and the feature exhibits a linear scan rate dependence (Fig. 2a, Inset). Assignment of another reduction behavior of Ni(II)\(^{2+}\) is ambiguous due to the overlap with a cathodic wave that appears on the control Si-CH\(_3\) surface. (Fig. S1, supporting information).

### Notes

\( ^{30} \)To demonstrate the molecular nature of the redox couple – and to investigate the local coordination environment – the surface was separately treated with excess PNP ligand in toluene for 1 h, then washed thoroughly with toluene and THF. First, it is noteworthy that the surface nickel was not abstracted by the PNP ligand in solution, again demonstrating the kinetic stability of the connected [Ni(II)]\(^2+\) Ni(PPh\(_3\))ClMeCNMeCN \((=\text{Ni-PNP}^1-\text{Ni})\) moiety.
metallated surface. XPS analysis of the resulting surface generated an N 1s feature roughly in a 1/2 ratio ($\theta_{N} = 41.9 \pm 4.9\%$) of the original metallated surface ($p$-Si(111)(C$_{6}$H$_{5}$)$_{2}$PNP-Ni(MeCN)$_{2}$, $\theta_{N}$ = 59.3 $\pm$ 13.4\%), indicating incorporation of a second equivalent of PNP ligand (and loss of two MeCN ligands) to the surface coordination environment. Additionally, the CV of the modified $p$-Si(111)(C$_{6}$H$_{5}$)$_{2}$PNP-Ni(II)-NiCN$_{2}$Br(CIO$_{4}$)$_{2}$ (= Si-PNP$^{2-}$-Ni) surface exhibits a redox feature that is anodically shifted by 0.18 V ($E_{1/2}$ for Ni(II/I) = $-0.03$ V vs NHE) to $-0.04$ V vs NHE. Such a result is expected based on the more facile access to the Ni(II/I) oxidation states in a softer P4-Ni$^{2+}$ coordination environment versus the P2/N2-Ni$^{3+}$ ligand set.$^{19}$ The Si-PNP$^{2-}$-Ni surface also exhibits a linear scan rate dependence (Fig. 2b, inset), indicative of the non-diffusive nature of the redox species. The covalently attached Ni coverage in the Si-PNP$^{2-}$-Ni surface was determined by Ni 2p XPS data as 19.1$\pm$5.7\% (Table 1). In previous work by others involving attachment of potential catalysts to Si(111), a fast loss of Rh was observed during several CV cycles.$^{11}$ Importantly, in this case the XPS data of the Si-PNP$^{2-}$-Ni sample after consecutive PEC-CV scans (30 cycles between $-0.3$ to $-1.6$ V vs Fc$^{+/0}$) revealed only a minor decrease (not statistically significant) in the Ni 2p coverage ($\theta_{Ni} = 15.6\%$, Table 1).

To demonstrate the catalytic function of the immobilized Ni(PNP)$_{2}$ surfaces, cathodic CVs were obtained in the presence of increasing concentrations of trifluorooracetic acid (TFA) in MeCN under N$_{2}$ (glove box). The resulting J-V traces of Si-PNP$^{2-}$-Ni and Si-PNP$^{3-}$-Ni show a similar shape (Fig. 3a and Fig. S2), respectively, and both samples demonstrate the characteristic increase in current. The current increase correlates with the generation of H$_{2}$ gas, which was confirmed by GC-MS analysis of the cell headspace in a controlled potential electrolysis (see experimental details in SI). The $V_{onset}$ of the Si-PNP$^{2-}$-Ni sample was noted at $0.06$ V vs NHE, and the $V_{onset} = -0.09$ V of the Si-PNP$^{3-}$-Ni (where $V_{onset} = E$ for 0.05 mA cm$^{-2}$; for comparison, the variation of the $V_{onset}$ threshold definition is plotted in Fig. S3, SI). The turnover frequency (TOF) of the Si-PNP$^{2-}$-Ni sample was calculated as 285 s$^{-1}$ from $j$ (A cm$^{-2}$) using 91 mM TFA at $-0.67$ V by an equation of TOF = $j/nFN$, where $n$ is the stoichiometric number of electrons consumed in the reaction ($n = 2$), $F$ is the Faraday constant, $N$ is the number of catalytic species. The amount of the confined Ni(PNP)$_{2}$ catalyst was determined to be 2.5 $\times$ 10$^{-10}$ mol cm$^{-2}$ (19.1\% coverage on Si(111) surface, where atop silicon $\sim 1.3 \times 10^{-9}$ mol cm$^{-2}$)$^{11}$. The acid dependence of the catalytic activity ($J_{max}$ vs [TFA]; Inset of Fig. 3a and Fig. S2) saturates for each sample near [TFA] = 90 mM. As a control experiment, the J-V curves for the corresponding substrate in the absence of Ni ion ($V_{onset}$ of $p$-Si(111)(C$_{6}$H$_{5}$)$_{2}$CH$_{3}$ = $-0.14$ V vs NHE, Fig. 3C (green line) and Fig. S4 in SI) indicate that Ni is responsible for the anodic shift of $V_{onset}$. Additionally, Pt nanoparticles (ALD deposition) on the p-Si(111)(C$_{6}$H$_{5}$)$_{2}$CH$_{3}$ (Fig. 3b) showed about 0.04 V more positive $V_{onset} (= -0.02$ V vs NHE) than the attached Si-PNP$^{2-}$-Ni sample. Once a suitably negative potential was applied ($< -0.3$ V vs NHE), the p-Si(111)(C$_{6}$H$_{5}$)Pt sample showed the fastest current increase, but the rise-to-max occurred relatively slowly in the low reduction potential range $> -0.3$ V (Fig. 3c). These results are comparable with a previous observation in an aqueous solution, wherein the p-Si(111)(C$_{6}$H$_{5}$)Pt surface exhibited a sharper $\Delta V$ ($V_{onset} - V_{max}$) than the p-Si(111)(CH$_{3}$)CH$_{3}$SiH$_{3}$ surface by 0.08 V.$^{32}$ The effect of the insulating methyl group on the Si surface seems to be dominant in the low reduction potential region. In contrast, the Ni(PNP)$_{2}$ catalyst, directly connected to Si through the phenyl ring, exhibited a comparatively rapid current increase near $-0.3$ V vs NHE. The overpotential of Si-PNP$^{2-}$-Ni was calculated as 0.34 V for 15.6 mM TFA (thermodynamic potential $E^{\theta}_{TFA} = -0.34$ V vs Fc$^{+/0}$ using Pt wire WE).

Lastly, as a control experiment we also investigated the photoelectrochemical behavior of the dissolved [Ni(PNP(C$_{6}$H$_{5}$)Br)$_{2}$]$^{2-}$ complex generated in situ (2 $\mu$M in MeCN), while using a $p$-Si(111)(C$_{6}$H$_{5}$)CH$_{3}$ working electrode. Interestingly, the non-attached catalyst [Ni(PNP(C$_{6}$H$_{5}$)Br)$_{2}$]$^{2-}$ (dashed line in Fig. 3d), exhibited a more negative $V_{onset}$ value of $-0.26$ V vs NHE – about 0.2 V more negative potential than the Si-PNP$^{2-}$-Ni construct – despite its electron-withdrawing p-bromo substituents. Thus, the semiconductor-catalyst construct exhibits a synergistic catalytic function that is greater than the ‘the sum of the parts’, as might be expected. The enhanced performance may also be due to expedited electron transfer to the Ni(PNP)$_{2}$ moiety by the (conjugated and covalent) phenyl linker.

Fig. 3 Catalytic CVs of functionalized substrates: (a) Si-PNP$^{2-}$-Ni (blue); (b) p-Si(111)(C$_{6}$H$_{5}$)CH$_{3}$/Pt control (black); (c) comparison of (a), (b), p-Si(111)(C$_{6}$H$_{5}$)CH$_{3}$ (green) samples, and Pt wire WE (red) at 15.6 mM TFA; (d) comparison of Si-PNP$^{2-}$-Ni (blue) and 2 $\mu$M [Ni(PNP(C$_{6}$H$_{5}$)Br)$_{2}$]$^{2-}$ solution on the Si(111)(C$_{6}$H$_{5}$)CH$_{3}$ surface (dashed). Insets: (a) [TFA] dependence at $-0.67$ V vs NHE; (b) [TFA] dependence at the indicated (red dashed line) potentials of $J_{max}$. Experiment conditions: N$_{2}$ atmosphere (glove box), 0.2 M LiClO$_{4}$ (MeCN), broadband LED 33 mW cm$^{-2}$, 100 mV s$^{-1}$ scan rate.

In closing, we have demonstrated the photo-electrochemical operation of a functional, molecular catalyst to a passivated Si surface. The earth abundance of the semiconductor (Si) and catalyst (Ni) is of particular note. The resulting Ni complex exhibits excellent stability during PEC-CV measurements in
provides a catalytic rate (TOF = ~ 285 s$^{-1}$) and resulting current (~20 mA cm$^{-2}$) that is commensurate with that expected of 1-sun illumination on Si (~25 mA cm$^{-2}$). Ongoing work is focused on modulation of the band-edge position, and higher catalytic turnover (by ligand selection) of the catalyst-functionalized substrate for improved solar→H$_2$ efficiency.

Notes and references

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† Electronic Supplementary Information (ESI) available: Procedures for Si etching, molecule attachments; PEC-CV figures; $V_{\text{aux}}$ definition are included. See DOI: 10.1039/b000000x/